NB7L585R

2.5V/3.3V, 7GHz/10Gbps Differential 2:1 Mux Input to 1:6 RSECL Clock/Data Fanout Buffer / Translator

Multi-Level Inputs w/ Internal Termination

Description

The NB7L585R is a differential 1:6 RSECL Clock/Data distribution chip featuring a 2:1 Clock/Data input multiplexer with an input select pin. The INx/\overline{INx} inputs incorporate internal 50 Ω termination resistors and will accept LVPECL, CML, or LVDS logic levels.

The NB7L585R produces six identical output copies of Clock or Data operating up to 7 GHz or 10 Gb/s, respectively. As such, NB7L585R is ideal for SONET, GigE, Fiber Channel, Backplane and other Clock/Data distribution applications.

The NB7L585R is powered with either 2.5 V or 3.3 V supply and is offered in a low profile 5mm x 5mm 32–pin QFN package.

Application notes, models, and support documentation are available at www.onsemi.com.

The NB7L585R is a member of the GigaComm $^{\text{TM}}$ family of high performance clock products.

Features

- Maximum Input Data Rate > 10 Gb/s Typical
- Data Dependent Jitter < 10 ps
- Maximum Input Clock Frequency > 7 GHz Typical
- www.Dat@sRandomoClock Jitter < 0.8 ps RMS
 - Low Skew 1:6 RSECL Outputs, 20 ps max
 - 2:1 Multi-Level Mux Inputs
 - 160 ps Typical Propagation Delay
 - 40 ps Typical Rise and Fall Times
 - Differential RSECL Outputs, 400 mV peak-to-peak, typical
 - Operating Range: $V_{CC} = 2.375 \text{ V}$ to 3.6 V with GND = 0 V
 - Internal 50 Ω Input Termination Resistors
 - VREFAC Reference Output
 - QFN-32 Package, 5mm x 5mm
 - -40°C to +85°C Ambient Operating Temperature
 - These Devices are Pb-Free and are RoHS Compliant



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QFN32 MN SUFFIX CASE 488AM

O NB7L 585R

AWLYYWW=

MARKING

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A = Assembly Location WL = Wafer Lot

YY = Year WW = Work Week • = Pb-Free Package

(Note: Microdot may be in either location)

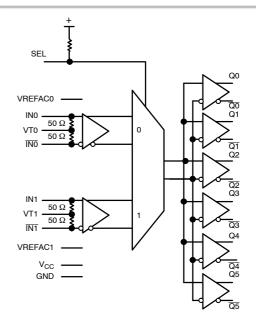


Figure 1. Simplified Block Diagram

ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

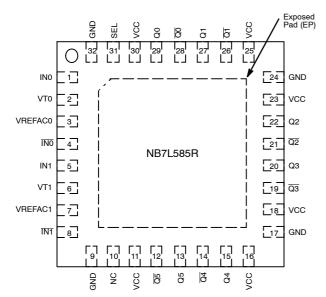


Figure 2. Pinout: QFN-32 (Top View)

Table 1. INPUT SELECT FUNCTION TABLE

SEL*	CLK Input Selected
0	INO
1	IN1

^{*}Defaults HIGH when left open.

Table 2. PIN DESCRIPTION

	Pin Number	Pin Name	I/O	Pin Description	
	1,4 5,8	IN0, <u>IN0</u> IN1, <u>IN1</u>	LVPECL, CML, LVDS Input	Non-inverted, Inverted, Differential Data Inputs internally biased to V _{CC} /2	
	2,6	VT0, VT1		Internal 100 Ω Center-tapped Termination Pin for IN0 / $\overline{\text{IN0}}$ and IN1 / $\overline{\text{IN1}}$	
	31	SEL	LVTTL/LVCMOS Input	Input Select pin; LOW for IN0 Inputs, HIGH for IN1 Inputs; defaults HIGH when left open	
	10	NC	-	No Connect	
	11, 16, 18 23, 25, 30	V _{CC}	-	Positive Supply Voltage. All $V_{\rm CC}$ pins must be connected to the positive power supply for correct DC and AC operation.	
vww.Daf	29, 28 27, 26 22, 21 20, 19 aShe 5, 14 aShe 13, 12	Q0, Q0 Q1, Q1 Q2,Q2 Q3, Q3 Q4, Q4 Q5, Q5	RSECL Output	Non-inverted, Inverted Differential Outputs Note 1.	
	9, 17, 24, 32	GND		Negative Supply Voltage, connected to Ground	
	3 7	VREFAC0 VREFAC1	-	Output Voltage Reference for Capacitor-Coupled Inputs	
	-	EP	-	The Exposed Pad (EP) on the QFN-32 package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be attached to a heat-sinking conduit. The pad is electrically connected to the die, and must be electrically and thermally connected to GND on the PC board.	

^{1.} In the differential configuration when the input termination pins (VT0, VT1) are connected to a common termination voltage or left open, and if no signal is applied on INn/INn input, then the device will be susceptible to self–oscillation.

^{2.} All V_{CC} and GND pins must be externally connected to a power supply for proper operation.

Table 3. ATTRIBUTES

Characteristi	Value				
ESD Protection Human Body Model Machine Model		> 2 kV > 200 V			
R _{PU} – SEL Input Pullup Resistor	37.5 kΩ				
Moisture Sensitivity (Note 3)	QFN-32	Level 1			
Flammability Rating	UL 94 V-0 @ 0.125 in				
Transistor Count	303				
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test					

^{3.} For additional information, see Application Note AND8003/D.

Table 4. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	Positive Power Supply	GND = 0 V		+4.0	V
V _{IO}	Input/Output Voltage	GND = 0 V		-0.5 to V _{CC} +0.5	V
V _{INPP}	Differential Input Voltage IN - ĪN			1.89	V
I _{IN}	Input Current Through R _T (50 Ω Resistor)			±40	mA
l _{out}	Output Current	Continuous Surge		50 100	mA
I _{VREFAC}	VREFAC Sink or Source Current			± 1.5	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient) (Note 4)	0 lfpm 500 lfpm	QFN32 QFN32	31 27	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case) (Note 4)		QFN32	12	°C/W
T _{sol}	Wave Solder			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

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^{4.} JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

Table 5. DC CHARACTERISTICS POSITIVE RSECL OUTPUT V_{CC} = 2.375 V to 3.6 V; GND = 0 V; T_A = -40°C to 85°C (Note 5)

Symbol	Characteristic	Min	Тур	Max	Uni
POWER S	UPPLY	•	•		
V _{CC}	Power Supply Voltage $V_{CC} = 3.3V_{CC} = 2.5V_{CC}$	3.0 2.375	3.3 2.5	3.6 2.625	V
Icc	Power Supply Current (Inputs and Outputs Open)		185	225	mA
RSECL O	utputs	•			
V _{OH}	Output HIGH Voltage (Note 6) $ \begin{array}{c} V_{CC} = 3.3 \text{ V} \\ V_{CC} = 2.5 \text{ V} \end{array} $	V _{CC} - 1300 2000 1200	V _{CC} – 1125 2175 1375	V _{CC} – 1000 2300 1500	m۷
V _{OL}	Output LOW Voltage (Note 6) $ V_{CC} = 3.3 \text{ V} $	V _{CC} – 1800 1500 700	V _{CC} – 1525 1775 975	V _{CC} – 1350 1950 1150	m\
DIFFEREN	NTIAL CLOCK INPUTS DRIVEN SINGLE-ENDED (Note 7) (Figures	s 5 & 6)	•		
V _{IH}	Single-ended Input HIGH Voltage	V _{th} + 100		V _{CC}	m\
V _{IL}	Single-ended Input LOW Voltage	GND		V _{th} – 100	m\
V _{th}	Input Threshold Reference Voltage Range (Note 8)	1100		V _{CC} -100	m\
V _{ISE}	Single-ended Input Voltage (V _{IH} - V _{IL})	200		V _{CC} – GND	m\
VREFACx	(for Capacitor- Coupled Inputs, Only)				
V _{REFAC}	Output Reference Voltage @100 μA for Capacitor - Coupled Inputs, Only	V _{CC} – 1350	V _{CC} – 1150	V _{CC} – 1000	m\
DIFFEREN	NTIAL INPUTS DRIVEN DIFFERENTIALLY (Figures 7 & 8) (Note 9)	•	•		
V_{IHD}	Differential Input HIGH Voltage (IN, IN)	1200		V _{CC}	m\
V _{ILD}	Differential Input LOW Voltage (IN , IN)	GND		V _{IHD} – 100	m\
V_{ID}	Differential Input Voltage (IN , $\overline{\text{IN}}$) (V _{IHD} – V _{ILD})	100		1200	m\
V _{CMR}	Input Common Mode Range (Differential Configuration, Note 10) (Figure 9)	1050		V _{CC} – 50	m\
I _{IH}	Input HIGH Current IN/IN (VTIN/VTIN Open)	-150		150	μA
I _{IL}	Input LOW Current IN/IN (VTIN/VTIN Open)	-150		150	μA
CONTROL	_ INPUT (SEL Pin)				
a ∀ heet4U.d	ollmput HIGH Voltage for Control Pin	2.0		V _{CC}	m\
V _{IL}	Input LOW Voltage for Control Pin	GND		0.8	m\
I _{IH}	Input HIGH Current	-150		150	μΔ
I _{IL}	Input LOW Current	-150		150	μA
TERMINA	TION RESISTORS				
R _{TIN}	Internal Input Termination Resistor (Measured from INx to VTx)	45	50	55	Ω
			· · · · · · · · · · · · · · · · · · ·		

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 5. Input and output parameters vary 1:1 with V $_{CC}$.
 6. RSECL outputs (Qn/Qn) loaded with 50 Ω to V $_{CC}$ 2 V for proper operation.
- 7. V_{th}, V_{IH}, V_{IL}, and V_{ISE} parameters must be complied with simultaneously.
- 8. V_{th} is applied to the complementary input when operating in single-ended mode.
- 9. V_{IHD} , V_{ILD} , V_{ID} and V_{CMR} parameters must be complied with simultaneously.
- 10. V_{CMR} min varies 1:1 with GND, V_{CMR} max varies 1:1 with V_{CC}. The V_{CMR} range is referenced to the most positive side of the differential input signal.

Table 6. AC CHARACTERISTICS $V_{CC} = 2.375 \text{ V to } 3.6 \text{ V}$; GND = 0 V; $T_A = -40 ^{\circ}\text{C}$ to 85°C (Note 11)

Symbol	Characteristic			Тур	Max	Unit
f _{MAX}	Maximum Input Clock Frequency; V _{OUTpp} ≥ 200 mV			7		GHz
f _{DATAMAX}	Maximum Operating Data Rate (PRBS23)		8	10		Gbps
f _{SEL}	Maximum Toggle Frequency, SEL		1.0	1.5		GHz
V_{OUTpp}	Output Voltage Amplitude (@ V _{INPPmin}) (Note 12) (Figures 8 and 10)	f _{in} ≤ 6.0 GHz	200	400		mV
t _{PLH} , t _{PHL}	Propagation Delay to Differential Outputs, @ 1 GHz, measured at differential crosspoint	IN/IN to Q/Q SEL to Q	100	160 200	225 300	ps
t _{PLH} TC	C Propagation Delay Temperature Coefficient			50		∆fs/°C
tskew	Output – Output skew (within device) (Note 13) Device – Device skew (tpd max – tpdmin)				20 100	ps
t _{DC}	Output Clock Duty Cycle (Reference Duty Cycle = 50%) $f_{in} \le 6.0 \text{ GHz}$		45	50	55	%
Φ_{N}	Phase Noise, f _c = 1 GHz 10 kHz 100 kHz 1 MHz 10 MHz 20 MHz 40 MHz			-134 -136 -149 -150 -151		dBc
t _{∫ΦN}	Integrated Phase Jitter (Figure x) $f_c = 1$ GHz, 12 kHz -2	20 MHz Offset (RMS)		36		fs
t _{JITTER}	$ \begin{array}{ll} \text{RJ} - \text{Output Random Jitter (Note 14)} & \text{$f_{\text{in}} \leq 5.0 \text{ GHz}$} \\ \text{DJ} - \text{Residual Output Deterministic Jitter (Note 15)} & \leq 8 \text{ Gbps} \end{array} $			0.2 2.0	0.8 10	ps RMS ps pk-pk
	Crosstalk Induced Jitter (Adjacent Channel) (Note 17)				0.7	ps RMS
V _{INPP}	Input Voltage Swing (Differential Configuration) (Note 16)		100		1200	mV
t _{r,} , t _f	Output Rise/Fall Times @ 1 GHz (20% - 80%), Q, Q		15	40	70	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 11. Measured using a 400 mV pk-pk source, 50% duty cycle clock source. All output loading with external 50 Ω to V_{CC} 2 V. Input edge rates 40 ps (20% 80%).
- 12. Output voltage swing is a single-ended measurement operating in differential mode.
- 13. Skew is measured between outputs under identical transitions and conditions. Duty cycle skew is defined only for differential operation when the delays are measured from cross–point of the inputs to the crosspoint of the outputs.
- www.Dat14 Additive RMS jitter with 50% duty cycle clock signal.
 - 15. Additive Peak-to-Peak data dependent jitter with input NRZ data at PRBS23.
 - 16. Input voltage swing is a single-ended measurement operating in differential mode.
 - 17. Crosstalk is measured at the output while applying two similar clock frequencies that are asynchronous with respect to each other at the inputs.

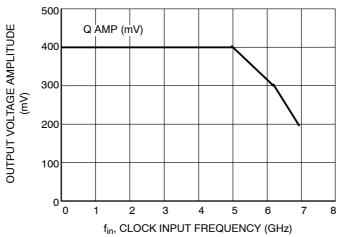


Figure 3. Clock Output Voltage Amplitude (V_{OUTpp}) vs. Input Frequency (f_{in}) at Ambient Temperature (Typical)

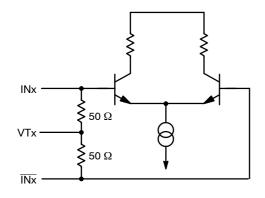


Figure 4. Input Structure

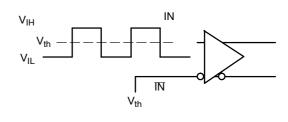


Figure 5. Differential Input Driven Single-Ended

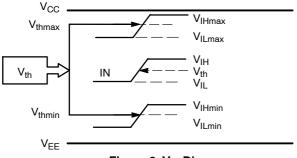


Figure 6. V_{th} Diagram

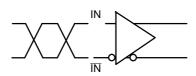
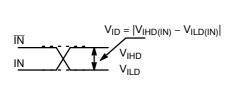


Figure 7. Differential Inputs Driven Differentially



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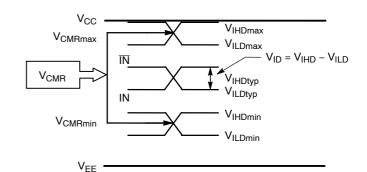


Figure 9. VCMR Diagram



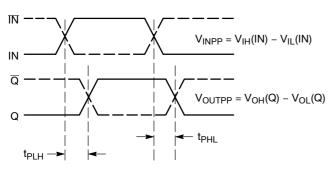


Figure 10. AC Reference Measurement

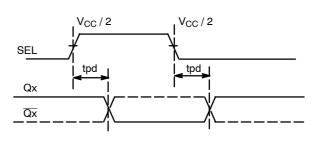


Figure 11. SEL to Qx Timing Diagram

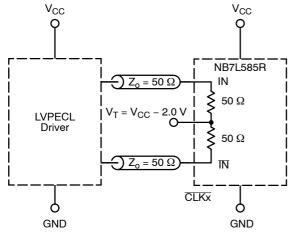


Figure 12. LVPECL Interface

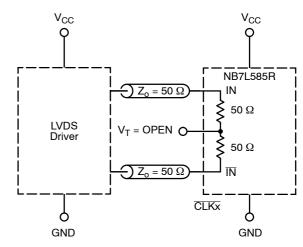


Figure 13. LVDS Interface

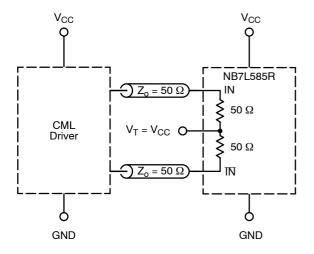


Figure 14. Standard 50 Ω Load CML Interface

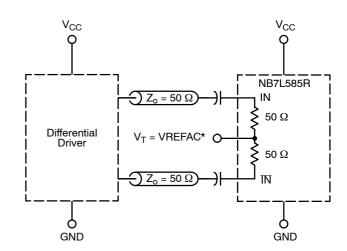


Figure 15. Capacitor–Coupled Differential Interface (V_T Connected to V_{REFAC})

*VREFAC bypassed to ground with a 0.01 μF capacitor.

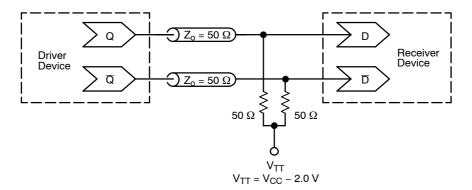


Figure 16. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

DEVICE ORDERING INFORMATION

Device	Package	Shipping [†]
NB7L585RMNG	QFN-32 (Pb-Free)	74 Units / Rail
NB7L585RMNR4G	QFN-32 (Pb-Free)	1000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

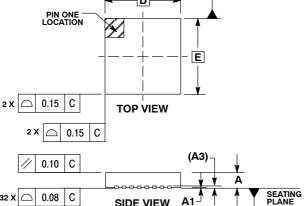
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PACKAGE DIMENSIONS

QFN32 5*5*1 0.5 P CASE 488AM-01 **ISSUE 0** В D

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SIDE VIEW

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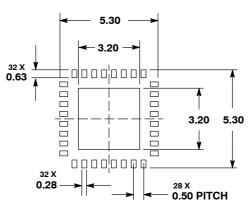
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- ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM TERMINAL
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS				
DIM	MIN	NOM	MAX		
Α	0.800	0.900	1.000		
A1	0.000	0.025	0.050		
А3	0.	200 REF	=		
b	0.180	0.250	0.300		
D	5	5.00 BSC			
D2	2.950	3.100	3.250		
Е	5	.00 BSC			
E2	2.950	3.100	3.250		
е	0.500 BSC				
K	0.200				
L	0.300	0.400	0.500		

EXPOSED PAD 32 X ՝ որոր^լոր հահ |25 0.10 С АВ Ф 0.05 С

SOLDERING FOOTPRINT*



BOTTOM VIEW

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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